Supporting Information

Hollow Cu-doped NiO microspheres as anode materials with enhanced lithium storage performance

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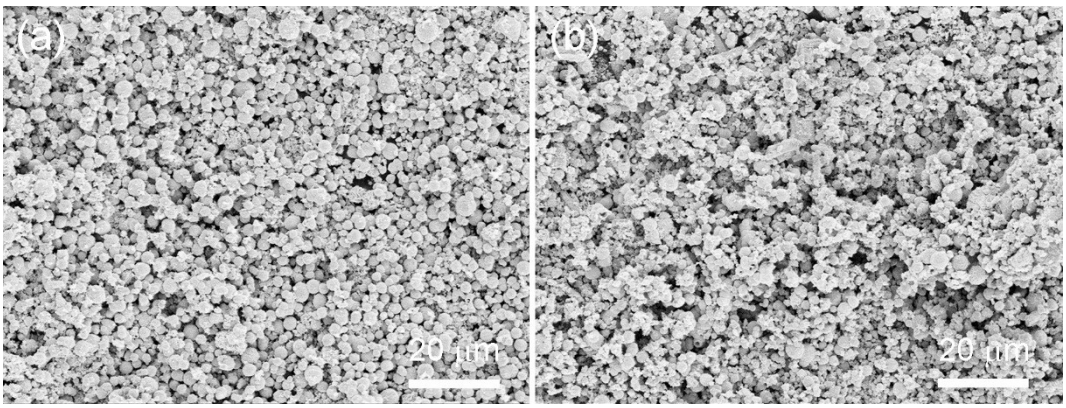

Fig. S1 Low magnification SEM images of (a) NiO and (b) Cu-doped NiO.

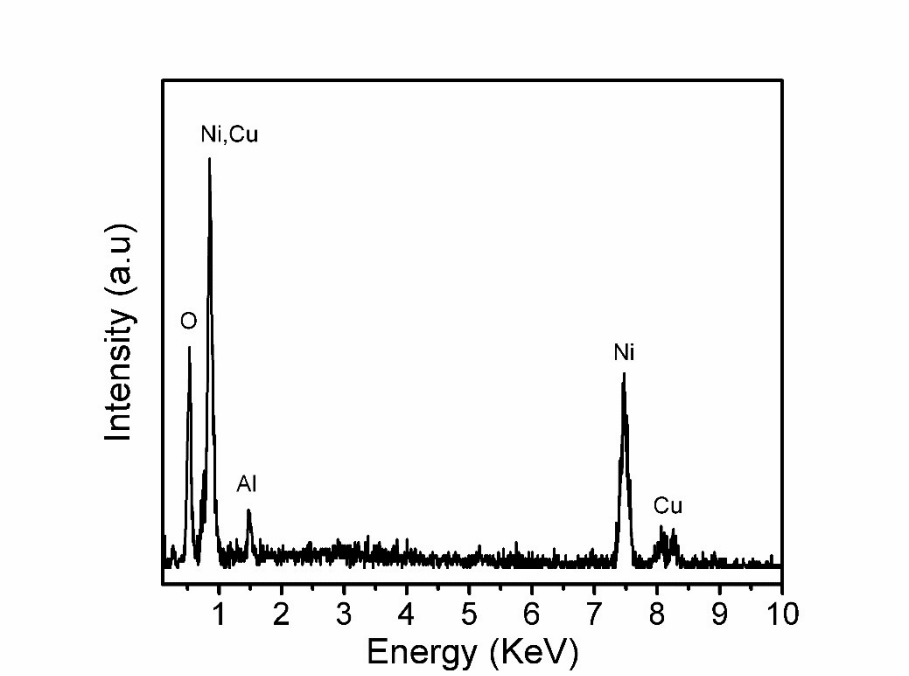

Fig. S2 EDS pattern of Cu-doped NiO.

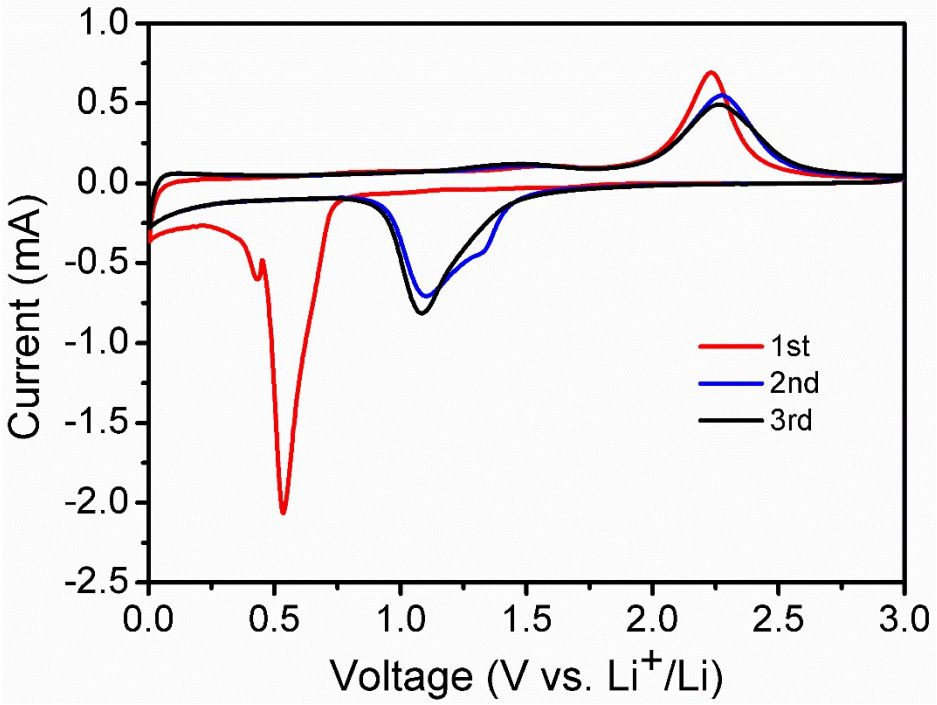

Fig. S3 First three consecutive CV curves of Cu-doped NiO at 0.1 mV s^{-1} scan rate.

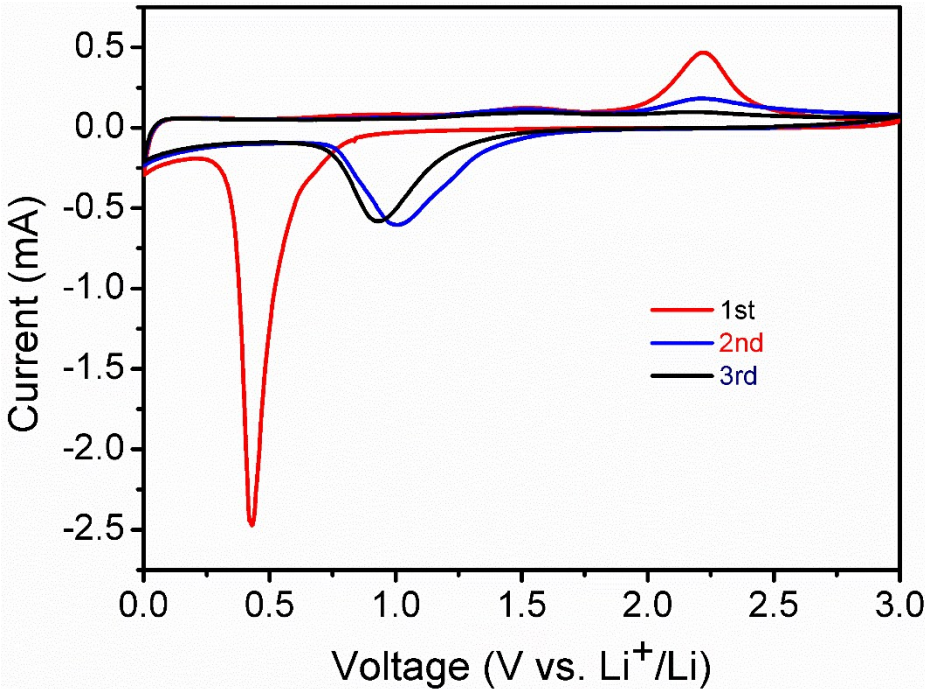

Fig. S4 First three consecutive CV curves of NiO at 0.1 mV s^{-1}.

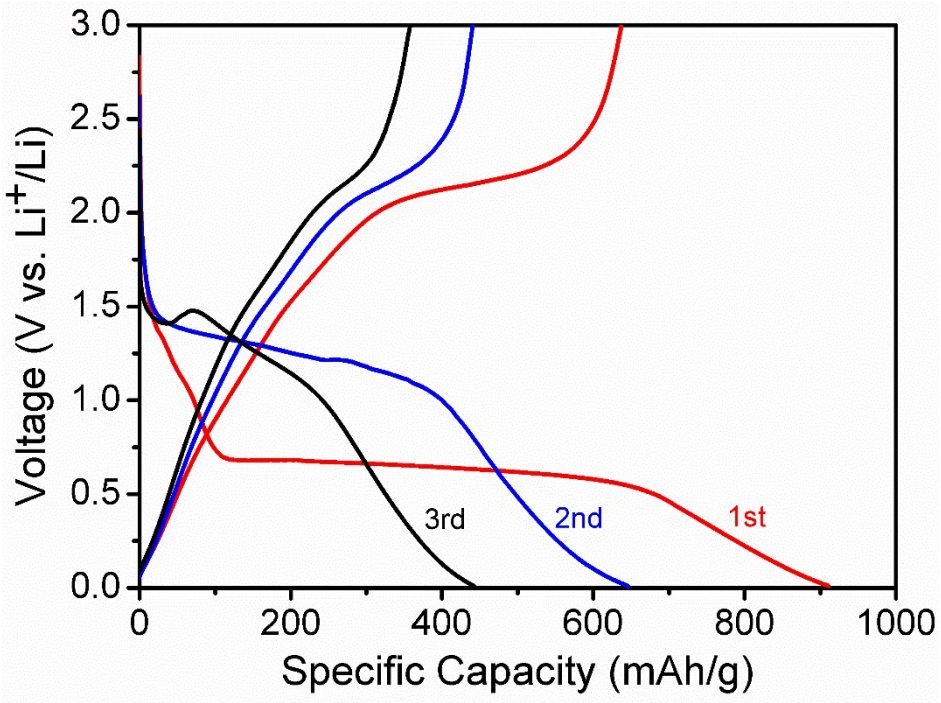

Fig. S5 Galvanostatic discharge and charge profiles of the 1st, 2nd and 3rd cycles of NiO at a current density of 100 mA g^{-1},